

9014

Rev.E Mar.-2016

TO-92

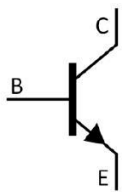
NPN

Silicon NPN transistor in a TO-92 Plastic Package.

P_C , h_{FE} , 9015

High P_C and h_{FE} excellent h_{FE} linearity, complementary pair with 9015.

Low frequency, low noise amplifier.



PIN1 Collector

PIN 2 Base

PIN 3 Emitter

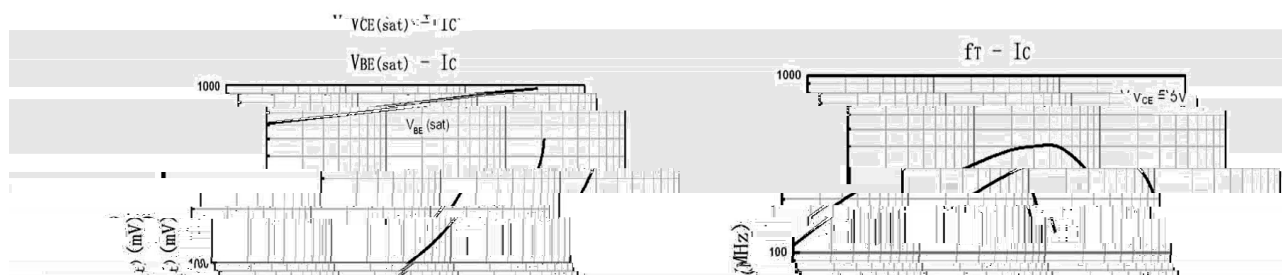
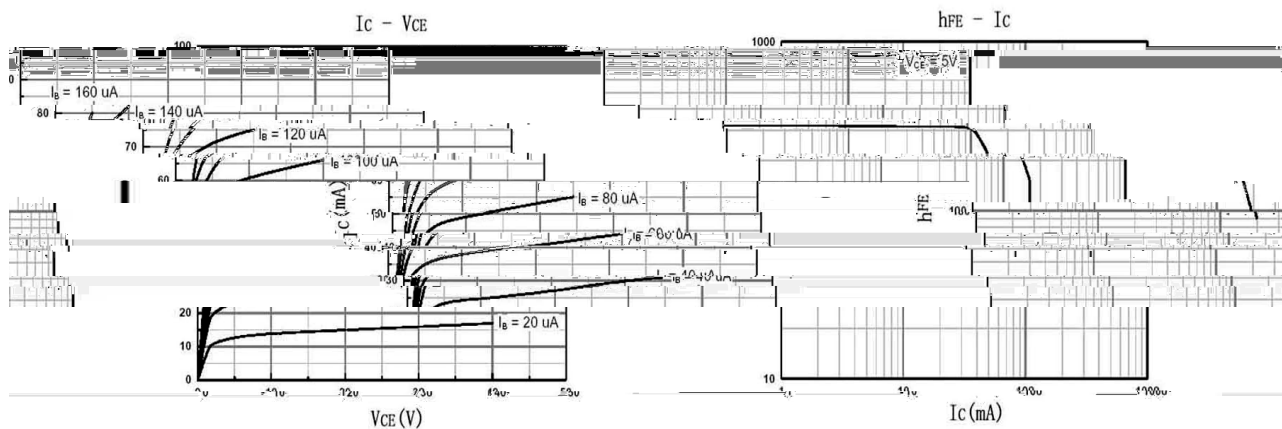
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	45	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	100	mA
Collector Power Dissipation	P_C	450	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=0.1mA$ $I_E=0$	50			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$ $I_B=0$	45			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=0.1mA$ $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=50V$ $I_E=0$			0.05	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.05	μA
DC Current Gain	h_{FE}	$V_{CE}=5.0V$ $I_C=1.0mA$	60		1000	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA$ $I_B=5.0mA$		0.14	0.3	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100mA$ $I_B=5.0mA$		0.84	1.0	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=5.0V$ $I_C=2.0mA$		0.63	0.7	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $I_C=10mA$	150	270		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $I_E=0$ $f=1.0MHz$		2.2	3.5	pF
Noise Figure	NF	$V_{CE}=5.0V$ $I_C=0.2mA$ $R_g=2.0K\Omega$ $f=1.0K\Omega$ $f=200Hz$		0.9	10	dB

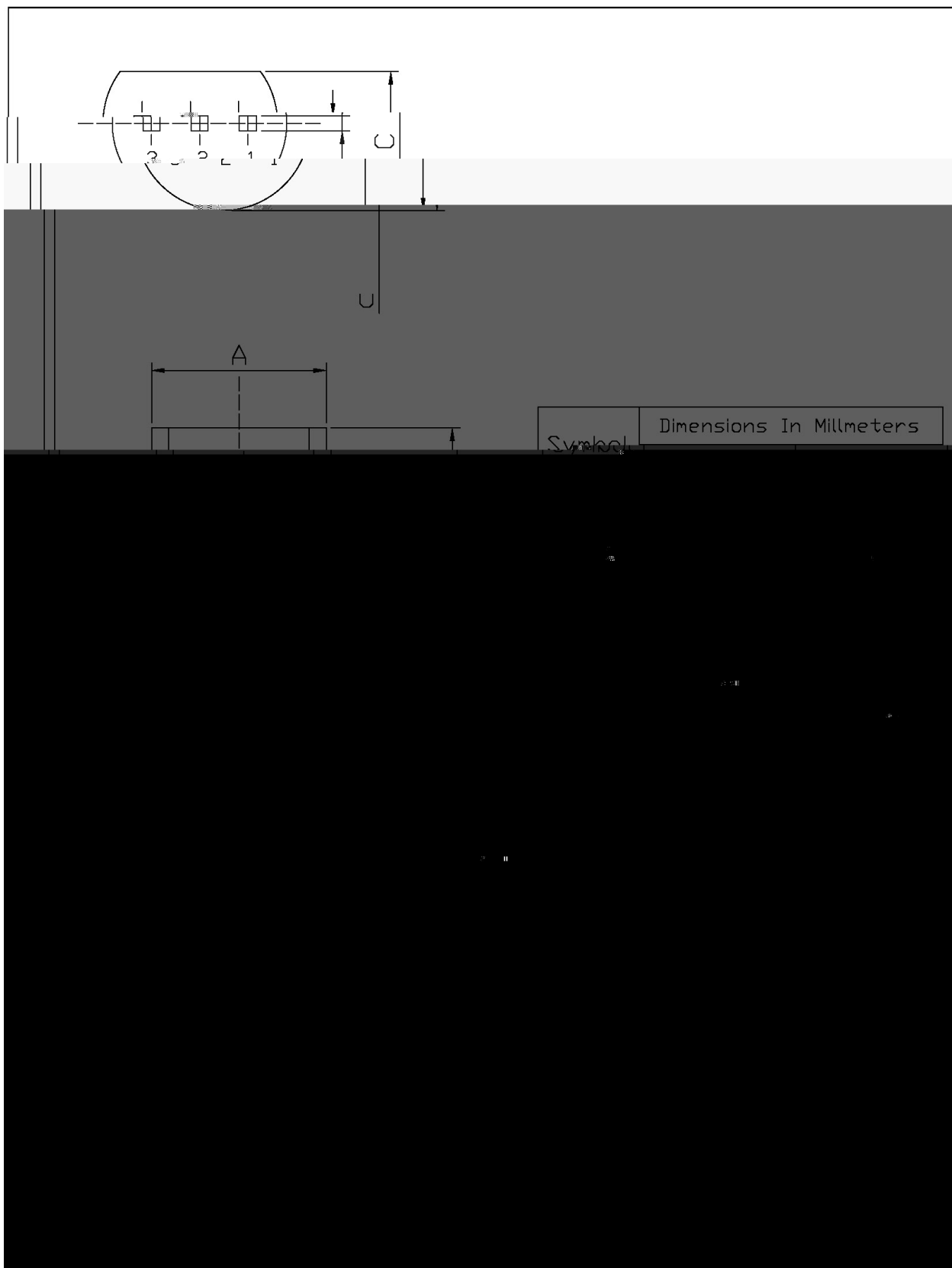
/ Electrical Characteristic Curve



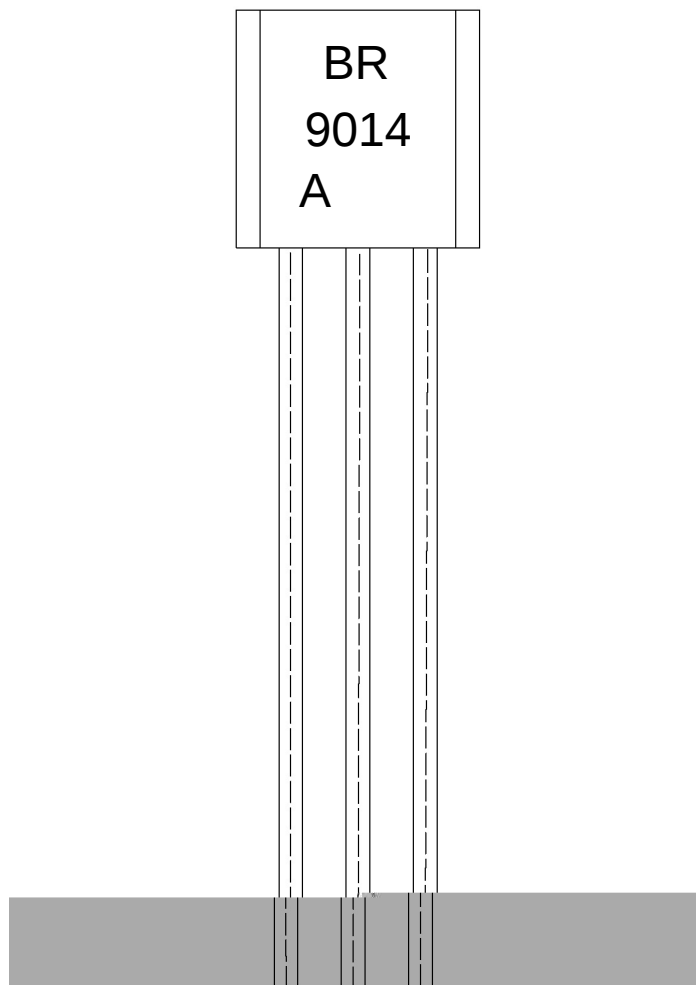
/ Package Dimensions

T O - 92

Unit: mm mm



/ Marking Instructions



BR

9014

A: h_{FE}

Note:

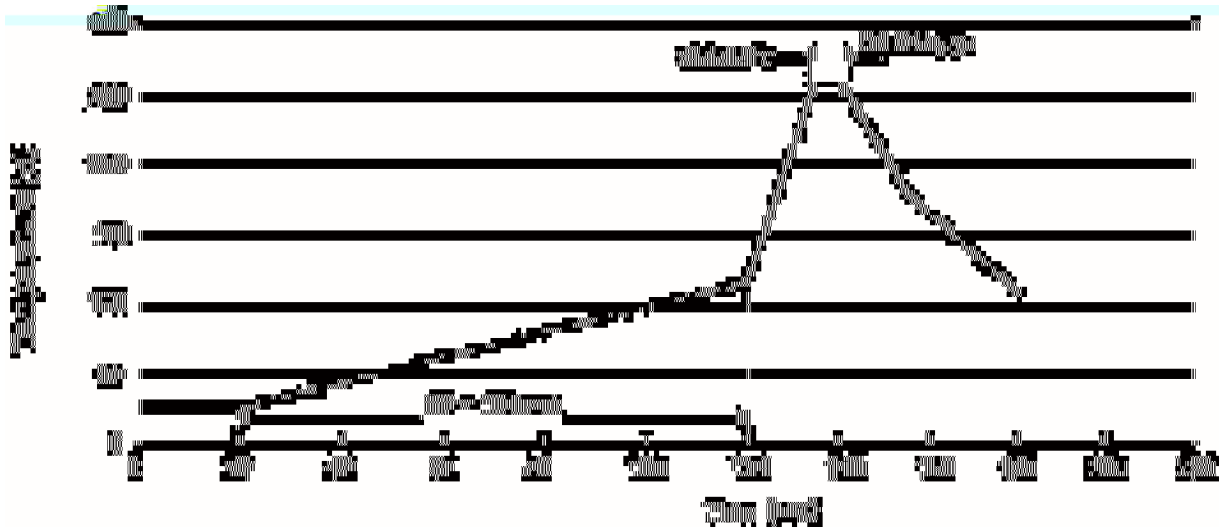
BR: Company Code.

9014: Product Type.

A: h_{FE} Classifications Symbol.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units					Dimension		(unit mm3)

/ AMMO

Package Type	Units					Dimension		(unit mm3)

/ Notices